ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND	
EXTCLK, SHDN to GND	0.3V to +6V
INV_, LP_, BP_, N_/HP_, S_, COM,	
CLK to GND	0.3V to (V _{DD} + 0.3V)
Maximum Current into Any Pin	50mA
Continuous Power Dissipation ($T_A = +70^\circ$	
16-Pin QSOP (derate 8.30mW/°C abov	e +70°C)667mW

Operating Temperature Range	
MAX749_CEE	0°C to +70°C
MAX749_EEE	40°C to +85°C
Die Temperature	+150°C
Storage Temperature	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS-MAX7490

 $(V_{DD} = V_{EXTCLK} = +5V; f_{CLK} = 625kHz; 10k\Omega \parallel 50pF$ load to $V_{DD}/2$ at LP_, BP_, and N_HP_; $V_{SHDN} = V_{DD}; 0.1\mu F$ from COM to GND; 50% duty-cycle clock input; COM = $V_{DD}/2$; $T_A = T_{MIN}$ to T_{MAX} . Typical values are at $T_A = +25^{\circ}C$, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
FILTER							
Center Frequency Range	fO	Mode 1		0.001 to 40		kHz	
Clock-to-Center Frequency Accuracy	fclk/fo	Mode 1, R1 = R3 = $50k\Omega$, R2 = $10k\Omega$, Q = 5, deviation from 100:1		±0.2	±0.7	%	
Q Accuracy		Mode 1, R1 = R3 = $50k\Omega$, R2 = $10k\Omega$, Q = 5		±0.2	±2	%	
f _O Temperature Coefficient				±1		ppm/°C	
Q Temperature Coefficient				±5		ppm/°C	
DC Lowpass Gain Accuracy		Mode 1, R1 = R2 = $10k\Omega$		±0.1	±0.5	%	
	VOS1	DC offset of input inverter		±3	±12.5		
DC Offset Voltage (Figure 8)	V _{OS2}	DC offset of 1st integrator		±4	±15 mV		
	V _{OS3}	DC offset of 2nd integrator		±4	±30	±30	
Crosstalk (Note 2)		f _{IN} = 10kHz		-60		dB	
		Input: COM externally driven	V _{DD} /2 - 0.5	V _{DD} /2	V _{DD} /2 + 0.5		
COM Voltage Range	Vсом	Output: COM internally driven	V _{DD} /2 - 0.2	V _{DD} /2	V _{DD} /2 + 0.2	V	
Input Resistance at COM	Rcom		140	250	325	kΩ	
Clock Feedthrough		Up to 5th harmonic of f _{CLK}		200		μV _{RMS}	
Noise (Note 3)		Mode 1, R1 = R2 = R3 =10k Ω , LP output, Q = 1		60		μV _{RMS}	
Output Voltage Swing			0.2		V _{DD} - 0.2	V	
Input Leakage Current at COM		$\overline{SHDN} = GND, V_{COM} = 0 \text{ to } V_{DD}$		±0.1	±10	μΑ	
CLOCK							
Maximum Clock Frequency	fCLK			4		MHz	
Internal Oscillator Frequency	fosc	EXTCLK = GND, C_{OSC} = 1000pF	95	135	175	kHz	
(Note 4)	1050	EXTCLK = GND, C_{OSC} = 100pF		1.35		MHz	
Clock Input High			V _{DD} - 0.5			V	

ELECTRICAL CHARACTERISTICS—MAX7490 (continued)

 $(V_{DD} = V_{EXTCLK} = +5V; f_{CLK} = 625 kHz; 10 k\Omega II 50 pF load to V_{DD}/2 at LP_, BP_, and N_HP_; V_{SHDN} = V_{DD}; 0.1 \mu F from COM to GND; 50% duty-cycle clock input; COM = V_{DD}/2; T_A = T_{MIN}$ to T_{MAX}. Typical values are at T_A = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Clock Input Low					0.5	V
Clock Duty Cycle				50 ± 5		%
SHDN AND EXTCLK						
Input High	VIH		V _{DD} - 0.5			V
Input Low	VIL				0.5	V
Input Leakage Current		$V_{INPUT} = 0$ to V_{DD}		±0.4	±10	μΑ
POWER REQUIREMENTS						
Supply Voltage	V _{DD}		4.5		5.5	V
Power-Supply Current	IDD	No external load, mode 1, R1 = R3 = $50k\Omega$, R2 = $10k\Omega$, Q = 5		3.5	4.0	mA
Shutdown Current	ISHDN	SHDN = GND			1	μΑ
INTERNAL OP AMPS CHARAC	CTERISTICS					
Output Short-Circuit Current				±18		mA
DC Open-Loop Gain		$R_L \ge 10k\Omega$, $C_L \le 50pF$		130		dB
Gain Bandwidth Product	GBW	$R_L \ge 10k\Omega$, $C_L \le 50pF$		7		MHz
Slew Rate	SR	$R_L \ge 10k\Omega$, $C_L \le 50pF$		6.4		V/µs



ELECTRICAL CHARACTERISTICS-MAX7491

 $(V_{DD} = V_{EXTCLK} = +3V; f_{CLK} = 625kHz; 10k\Omega II 50pF load to V_{DD}/2 at LP_, BP_, and N_/HP_; V_{SHDN} = V_{DD}; 0.1\muF from COM to GND; 50% duty-cycle clock input; COM = V_{DD}/2; T_A = T_{MIN}$ to T_MAX. Typical values are at T_A = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ΤΥΡ	MAX	UNITS	
FILTER							
Center Frequency Range	fO	Mode 1		0.001 to 40		kHz	
Clock-to-Center Frequency Accuracy	fCLK/fO	Mode 1, R1 = R3 = $50k\Omega$, R2 = $10k\Omega$, Q = 5, deviation from 100:1		±0.2	±0.7	%	
Q Accuracy		Mode 1, R1 = R3 = $50k\Omega$, R2 = $10k\Omega$, Q = 5		±0.2	±2	%	
fo Temperature Coefficient				±1		ppm/°C	
Q Temperature Coefficient				±5		ppm/°C	
DC Lowpass Gain Accuracy		Mode 1, R1 = R2 = $10k\Omega$		±0.1	±0.5	%	
	Vos1	DC offset of input inverter		±3	±12.5		
DC Offset Voltage (Figure 8)	V _{OS2}	DC offset of 1st integrator		<u>±</u> 4	±15	mV	
(rigure b)	V _{OS3}	DC offset of 2nd integrator		±4	±25		
Crosstalk (Note 2)		$f_{IN} = 10 kHz$		-60		dB	
		Input: COM externally driven	V _{DD} /2 - 0.1	V _{DD} /2	V _{DD} /2 + 0.1		
COM Voltage Range	Vсом	Output: COM internally driven	V _{DD} /2 - 0.1	V _{DD} /2	V _{DD} /2 + 0.1		
Input Resistance at COM	Rcom		60	80	120	kΩ	
Clock Feedthrough		Up to 5th harmonic of f _{CLK}		200		μV _{RMS}	
Noise (Note 3)		Mode 1, R1= R2 = R3 = 10k Ω , LP output, Q = 1		60		μV _{RMS}	
Output Voltage Swing			0.2		V _{DD} - 0.2	V	
Input Leakage Current at COM		$\overline{\text{SHDN}} = \text{GND}, \text{V}_{\text{COM}} = 0 \text{ to } \text{V}_{\text{DD}}$		±0.1	±10	μΑ	
CLOCK							
Maximum Clock Frequency	fCLK			4		MHz	
Internal Oscillator Frequency	fosc	EXTCLK = GND, C_{OSC} = 1000pF	95	135	175	kHz	
(Note 4)	IOSC	EXTCLK = GND, C_{OSC} = 100pF		1.35		MHz	
Clock Input High			V _{DD} - 0.5			V	
Clock Input Low					0.5	V	
Clock Duty Cycle				50 ±5		%	
SHDN AND EXTCLK							
Input High	VIH		V _{DD} - 0.5			V	
Input Low	VIL				0.5	V	
Input Leakage Current		$V_{INPUT} = 0$ to V_{DD}		±0.4	±10	μΑ	

ELECTRICAL CHARACTERISTICS—MAX7491 (continued)

(VDD = VEXTCLK = +3V; fCLK = 625kHz; 10kΩ II 50pF load to VDD/2 at LP_, BP_, and N_/HP_; VSHDN = VDD; 0.1µF from COM to GND; 50% duty-cycle clock input; COM = V_{DD}/2; T_A = T_{MIN} to T_{MAX}. Typical values are at T_A = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
POWER REQUIREMENTS							
Supply Voltage	V _{DD}		2.7		3.6	V	
Power-Supply Current	IDD	No load, mode 1, R1 = R3 = 50k Ω , R2 = 10k Ω , Q = 5		3.5	4.0	mA	
Shutdown Current	ISHDN	SHDN = GND			1	μΑ	
INTERNAL OP AMPS CHARACT	ERISTICS						
Output Short-Circuit Current				±11		mA	
DC Open-Loop Gain		$R_L \ge 10k\Omega$, $C_L \le 50pF$		130		dB	
Gain Bandwidth Product	GBW	$R_L \ge 10k\Omega, C_L \le 50pF$ 7			MHz		
Slew Rate	SR	$R_L \ge 10k\Omega$, $C_L \le 50pF$		6		V/µs	

Note 1: Resistive loading of the N_/HP_, LP_, BP_ outputs includes the resistors used for the filter implementation.

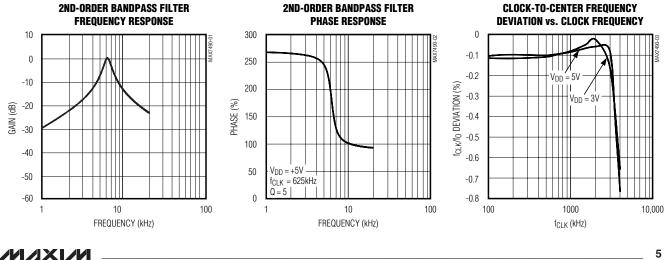
Note 2: Crosstalk between internal filter sections is measured by applying a 1V_{RMS} 10kHz signal to one bandpass filter section input and grounding the input of the other bandpass filter section. The crosstalk is the ratio between the output of the grounded filter section and the 1V_{RMS} input signal of the other section.

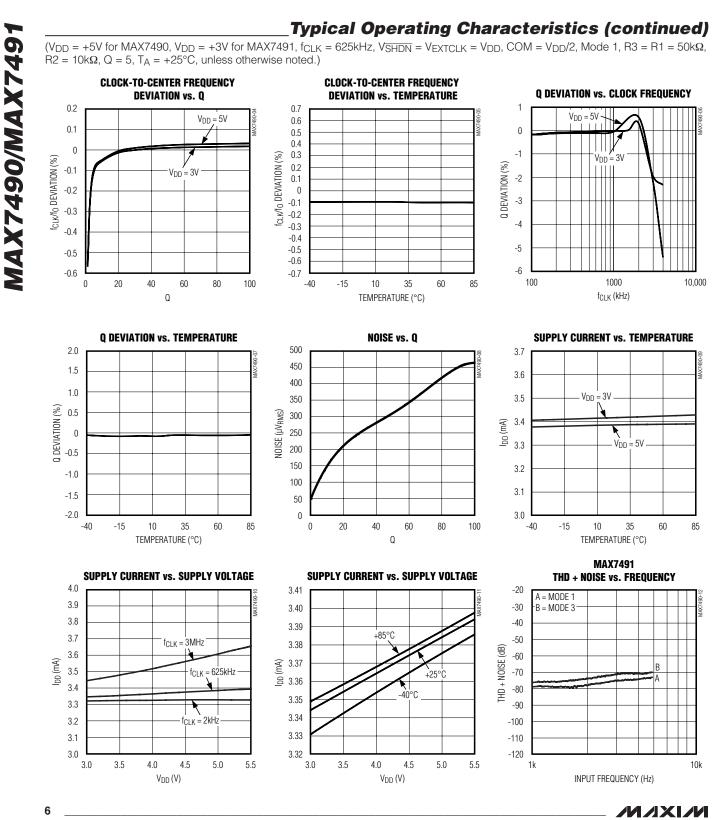
Note 3: Bandwidth of noise measurement is 80kHz.

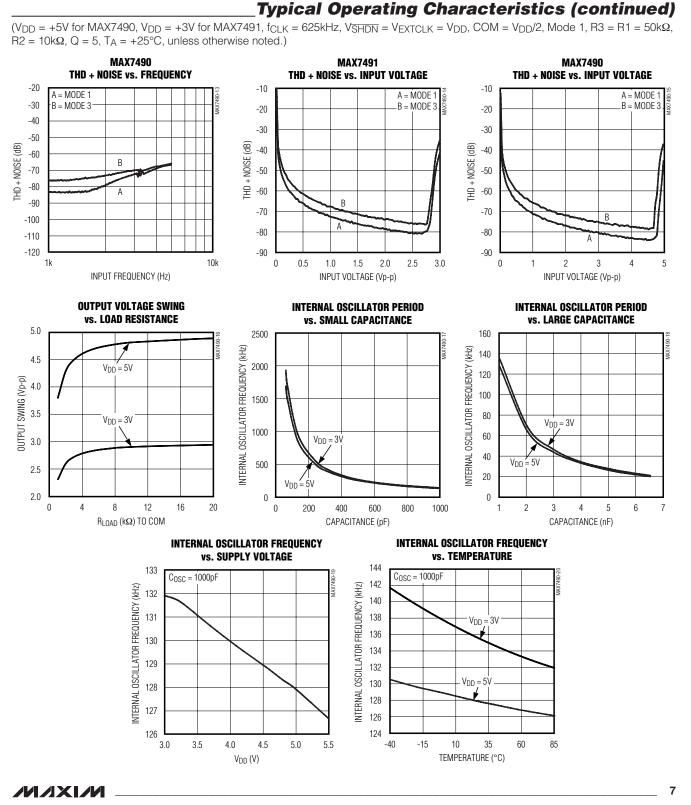
Note 4: f_{OSC} (kHz) = 135 x 10³ / C_{OSC} (C_{OSC} in pF)

Typical Operating Characteristics

 $(V_{DD} = +5V \text{ for MAX7490}, V_{DD} = +3V \text{ for MAX7491}, f_{CLK} = 625 \text{kHz}, V_{SHDN} = V_{EXTCLK} = V_{DD}, COM = V_{DD}/2, Mode 1, R3 = R1 = 50 \text{k}\Omega$ $R2 = 10k\Omega$, Q = 5, $T_A = +25^{\circ}C$, unless otherwise noted.)







MAX7490/MAX7491

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DIN	NA	ME	FUNCTION
PIN	FILTER A	FILTER B	FUNCTION
LP_	1	16	2nd-Order Lowpass Filter Output
BP_	2	15	2nd-Order Bandpass Filter Output
N_/HP_	3	14	2nd-Order Notch/Highpass Filter Output
INV_	4	13	Inverting Input of Filter Summing Op Amp
S_	5	12	Summing Input. The connection of the summing input, along with the other resistor connections, determine the circuit topology (mode) of each 2nd-order section. S_ must never be left unconnected.
SHDN	6		Shutdown Input. Drive \overline{SHDN} low to enable shutdown mode; drive \overline{SHDN} high or connect to V_{DD} for normal operation.
GND	7		Ground Pin
V _{DD}	8		Positive Supply. Bypass V_{DD} with a 0.1µF capacitor to GND. A low-noise supply is recommended. Input +5V for MAX7490 or +3V for MAX7491.
CLK	9		Clock Input. Connect CLK to an external capacitor (C_{OSC}) between CLK and ground to set the internal oscillator frequency. For external clock operation, drive CLK with a CMOS-level clock. The duty cycle of the external clock should be between 45% and 55% for best performance.
EXTCLK	10		External/Internal Clock Select Input. Connect EXTCLK to V _{DD} when driving CLK externally. Connect EXTCLK to GND when using the internal oscillator.
СОМ	11		Common Pin. Biased internally at $V_{DD}/2$. Bypass externally to GND with 0.1µF capacitor. To override the internal biasing, drive COM with an external low-impedance source.

Detailed Description

The MAX7490/MAX7491 are universal switched-capacitor filters designed with a fixed internal f_{CLK}/f_0 ratio of 100:1. Operating modes use external resistors connected in different arrangements to realize different filter functions (highpass, lowpass, bandpass, notch) in all of the classical filter topologies (Butterworth, Bessel, elliptic, Chebyshev). Figure 1 shows a block diagram.

Clock Signal

External Clock

The MAX7490/MAX7491 switched-capacitor filters are designed for use with external clocks that have a 50% \pm 5% duty cycle. When using an external clock, drive the EXTCLK pin high or connect to V_{DD}. Drive CLK with CMOS logic levels (GND and V_{DD}). Varying the rate of

the external clock adjusts the center frequency of the filter:

$$f_O = f_{CLK} / 100$$

Internal Clock

///XI///

When using the internal oscillator, drive the EXTCLK pin low or connect to GND and connect a capacitor (C_{OSC}) between CLK and GND. The value of the capacitor (C_{OSC}) determines the oscillator frequency as follows:

$$f_{OSC}$$
 (kHz) = 135 x 10³ / C_{OSC} (pF)

Since C_{OSC} is in the low picofarads, minimize the stray capacitance at CLK so that it does not affect the internal oscillator frequency. Varying the frequency of the internal oscillator adjusts the filter's center frequency by a 100:1 clock-to-center frequency ratio. For example, an internal oscillator frequency of 135kHz produces a nominal center frequency of 1.35kHz.



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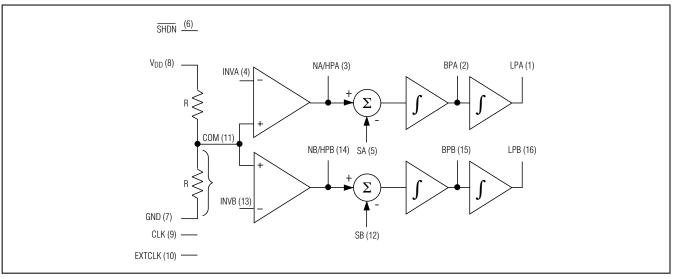


Figure 1. Block Diagram

2nd-Order Filter Stage

The MAX7490/MAX7491 are dual biquad filters. The biquad topology allows the use of standard filter tables and equations to implement simultaneous lowpass, bandpass, and notch or highpass filters. Topologies such as Butterworth, Chebyshev, Bessel, elliptic, as well as custom algorithms are possible.

Internal Common Voltage

The COM pin sets the common-mode input voltage and is internally biased to $V_{DD}/2$ with a resistor-divider. The resistors used are typically 250k Ω for the MAX7490, and typically 80k Ω for the MAX7491. The common-mode voltage is easily overdriven by an external voltage supply if desired. Bypass COM to the analog ground with at least a 0.1µF capacitor.

Inverting Inputs

Outputs

Locate resistors that are connected to INV_ as close as possible to INV_ to reduce stray capacitance and noise pickup. INV_ are inverting inputs to continuous-time op amps, and behave like a virtual ground. There is no sampling energy present on these inputs.

Each switched-capacitor section, together with two to four external resistors, can generate all standard 2ndorder functions: bandpass, lowpass, highpass, and notch (band-reject) functions. Three of these functions are simultaneously available. The maximum signal swing is limited by the power-supply voltages used. The amplifiers' outputs in the MAX7490/MAX7491 are able to swing to within approximately 0.2V of either supply.

Driving coaxial cable, large capacitive loads, or total resistive loads less than $10k\Omega$ will degrade the total harmonic distortion (THD) performance. Note that the effective resistive load at the output must include both the feedback resistors and any external load resistors.

Low-Power Shutdown Mode

The MAX7490/MAX7491 have a shutdown mode that is activated by driving SHDN low. In shutdown mode, the filter supply current reduces to < 1μ A (max), and the filter outputs become high impedance. The COM input also becomes high impedance during shutdown. For normal operation, drive SHDN high or connect to V_{DD}.

Applications Information

Designing with the MAX7490/MAX7491 begins by selecting the mode that best fits the desired circuit requirements. Table 1 lists the available modes and their relative advantages and disadvantages. Table 2 lists the different nomenclature used in the explanations that follow.



MAX7490/MAX7491

MODE	LP	HP	BP	Ν	LP-N*	HP-N*	COMMENTS
1	•		•	•			f _{CLK} /f _O ratio is the nominal value. Good for bandpass filters with identical sections cascaded, higher order Butterworth filters, high-Q bandpass, low-Q notches.
1B	٠		•	•			Same as Mode 1 with $f_{\text{CLK}}/f_{\text{O}}$ ratios greater than the nominal value.
2	•		•	•			Combination of Mode 1 and Mode 3; f _{CLK} /f _O ratios always less than the nominal value. Less sensitivity to resistor tolerances than Mode 3.
2N					•		Extension of Mode 2 that allows higher frequencies. Highpass and lowpass outputs are summed with external op amp and two resistors. Good for lowpass elliptic filters.
3	•	•	•				Adjustable fo above and below the nominal frequency. Commonly used for multiple-pole Chebyshev filters, all-pole higher order bandpass, lowpass, and highpass filters.
3A	•	•	•		•	•	Extension of Mode 3 that needs an external op amp and two additional resistors. Commonly used for lowpass or higher elliptic or Cauer filters.

Table 1. Filter Operating Modes

*LP-N = lowpass notch, HP-N = highpass notch. Both require an external op amp. See Definition of Terms (Table 2).

Table 2. Definition of Terms

TERM	DEFINITION
fCLK	The clock frequency applied to the switched-capacitor filter.
fO	The center frequency of the 2nd-order complex pole pair, f_0 , is determined by measuring the peak response frequency at the bandpass output.
f NOTCH	The frequency of minimum amplitude response at the notch output.
Q	Quality factor, or Q, is the ratio of f_O to the -3dB bandwidth of the 2nd-order bandpass filter. Q also determines the amount of amplitude peaking at the lowpass and highpass outputs, but is not measured at these outputs.
HOBP	The gain in V/V of the bandpass output at $f = f_O$.
HOLP	The gain in V/V of the lowpass output at $f\rightarrow$ 0Hz.
HOHP	The gain in V/V of the highpass output at $f \rightarrow f_{CLK}/2$.
Hon1	The notch output gain as $f \rightarrow 0Hz$.
H _{ON2}	The notch output gain at $f = f_{CLK}/2$.
LP-N	A notch output with H _{ON1} > H _{ON2} .
HP-N	A notch output with H _{ON1} < H _{ON2} .

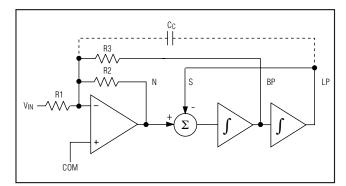


Figure 2. Mode 1, 2nd-Order Filter Providing Notch, Bandpass, and Lowpass Outputs

Mode 1

Figure 2 shows the MAX7490/MAX7491s' configuration of Mode 1. This mode provides 2nd-order notch, lowpass, and bandpass filter functions. The gain at all three outputs is inversely proportional to the value of R1. The center frequency, fO, is fixed at f_{CLK}/100. High-Q bandpass filters can be built without exceeding the bandpass amplifier's output swing (i.e., HOBP does not have to track Q). The notch and bandpass center frequencies are identical. The notch output gain is the same above and below the notch center frequency. Mode 1 can also be used to make high-order Butterworth lowpass filters, low Q notches, and multiple-order bandpass filters obtained by cascading identical switched-capacitor sections.

Mode 1 Design Equations

$$f_{O} = \frac{f_{CLK}}{100}$$

$$f_{notch} = f_{O}$$

$$Q = \frac{R3}{R2}$$

$$H_{OLP} = \frac{-R2}{R1}$$

$$H_{OBP} = \frac{-R3}{R1}$$

$$H_{ON1}(as f \rightarrow 0Hz) = \frac{-R2}{R1}$$

$$H_{ON2}(at f = f_{CLK} / 2) = \frac{-R2}{R1}$$

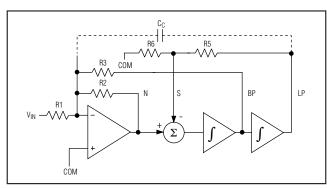


Figure 3. Mode 1B, 2nd-Order Filter Providing Notch, Bandpass, and Lowpass Outputs

Mode 1B

Figure 3 shows the configuration of Mode 1B. R5 and R6 are added to lower the feedback voltage from the lowpass output to the summing input. This allows the clock-to-center frequency to be adjusted beyond the nominal value. This mode essentially has the same functions and speed as Mode 1 while providing a high-Q with f_{CLK}/f_O ratios greater than the nominal value.

Mode 1B Design Equations

$$f_{O} = \frac{f_{CLK}}{100} \sqrt{\frac{R6}{R6 + R5}}$$

$$f_{n} = f_{O}$$

$$Q = \frac{R3}{R2} \sqrt{\frac{R6}{R6 + R5}}$$

$$H_{OLP} = \frac{-R2}{R1} \frac{R6 + R5}{R6}$$

$$H_{OBP} = \frac{-R3}{R1}$$

$$H_{ON1}(as f \rightarrow 0Hz) = \frac{-R2}{R1}$$

$$H_{ON2}(at f = f_{CLK} / 2) = \frac{-R2}{R1}$$

Mode 2

Figure 4 shows the configuration of Mode 2. Mode 2 is a combination of Mode 1 and Mode 3. In this mode, f_{CLK}/f_O is always less than the part's nominal ratio. However, it provides less sensitivity to resistor tolerances than does Mode 3. It has a highpass notch output where the notch frequency depends solely on the clock frequency.



$$f_{O} = \frac{f_{CLK}}{100} \sqrt{1 + \frac{R2}{R4}}$$

$$f_{n} = \frac{f_{CLK}}{100}$$

$$Q = \frac{R3}{R2} \sqrt{1 + \frac{R2}{R4}}$$

$$H_{OLP} = \frac{-R2}{R1} \left(\frac{R4}{R4 + R2}\right)$$

$$H_{OBP} = \frac{-R3}{R1}$$

$$H_{ON1}(f \rightarrow 0Hz) = \frac{-R2}{R1} \left(\frac{R4}{R4 + R2}\right)$$

$$H_{ON2}(at f = f_{CLK} / 2) = \frac{-R2}{R1}$$



Figure 5 shows the configuration of Mode 2N. This mode extends the topology of Mode 3A to Mode 2, where the highpass and lowpass outputs are summed through two external resistors, R_H and R_L , to create a lowpass notch filter that has higher frequency than the one in Mode 2. Mode 2 is most useful in lowpass elliptic designs. When cascading the sections of the MAX7490/MAX7491, the highpass and lowpass outputs can be summed directly into the inverting input of the next section. Only one external op amp is needed.

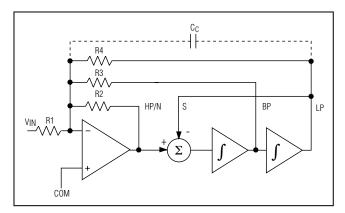


Figure 4. Mode 2, 2nd-Order Filter Providing a Highpass Notch, Bandpass, and Lowpass Outputs

Mode 2N Design Equations

$$f_{O} = \frac{f_{CLK}}{100} \sqrt{1 + \frac{R2}{R4}}$$

$$f_{n} = \frac{f_{CLK}}{100} \sqrt{1 + \frac{R_{H}}{R_{L}}}$$

$$Q = \frac{R3}{R2} \sqrt{1 + \frac{R2}{R4}}$$

$$H_{ON1}(f \rightarrow 0Hz) = \left(\frac{R_{G}}{R_{H}} + \frac{R_{G}}{R_{L}}\right) \left(\frac{R2}{R1}\right) \left(\frac{R4}{R4 + R2}\right)$$

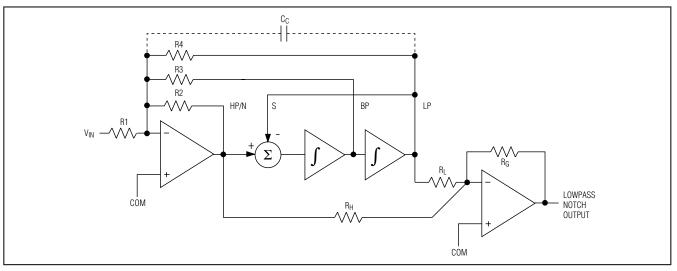


Figure 5. Mode 2N, 2nd-Order Filter Providing a Lowpass Notch Output

Mode 3

Figure 6 shows the configuration of Mode 3. This mode is a sampled time (Z transform) equivalent of the classical 2nd-order state variable filter. In this versatile mode, the ratio of resistors R2 and R4 can move the center frequency both above and below the nominal ratio. Mode 3 is commonly used to make multiple-pole Chebyshev filters with a single clock frequency. This mode can also be used to make high-order all-pole bandpass, lowpass, and highpass filters.

Mode 3 Design Equations

$$f_{O} = \frac{f_{OLK}}{100} \sqrt{\frac{R2}{R4}}$$
$$Q = \frac{R3}{R2} \sqrt{\frac{R2}{R4}}$$
$$H_{OHP} = \frac{-R2}{R1}$$
$$H_{OLP} = \frac{-R4}{R1}$$
$$H_{OBP} = \frac{-R3}{R1}$$

Mode 3A

Figure 7 shows the configuration of Mode 3A. Similar to Mode 2, this mode adds an external op amp. See Table 3 for op amp selection ideas. This op amp creates a highpass notch and lowpass notch by summing

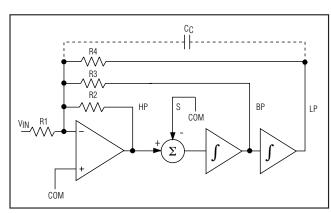


Figure 6. Mode 3, 2nd-Order Section Providing Highpass, Bandpass, and Lowpass Outputs

the highpass and lowpass outputs through two external resistors, R_H and R_L. The ratio of resistors R_H and R_L adjusts the notch frequency, while R2 and R4 adjust the bandpass center frequency, since the notch (zero pair) frequency can be adjusted to both above and below f_O. Mode 3A is suitable for both lowpass and highpass elliptic or Cauer filters. In multipole elliptic filters, only one external op amp is needed. Use the inverting input of the internal op amp as the summing node for all but the final section of the filter.

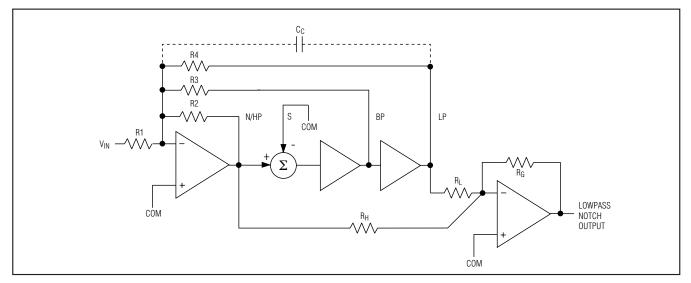


Figure 7. Mode 3A, 2nd-Order Filter Providing Highpass Notch or Lowpass Notch Outputs

PART	GBW (MHz)	SLEW RATE (V/µs)	ISUPPLY/AMP (mA)	PIN-PACKAGE
MAX4281	2	0.7	0.5	5 SOT23
MAX4322	5	2.0	1.1	5 SOT23
MAX4130	10	4.0	1.15	5 SOT23
MAX4490	10	10.0	2.0	5 SOT23

Table 3. Suggested External Op Amps

Mode 3A Design Equations

$$f_{O} = \frac{f_{CLK}}{100} \sqrt{\frac{R2}{R4}}$$

$$f_{n} = \frac{f_{CLK}}{100} \sqrt{\frac{R_{H}}{R_{L}}}$$

$$Q = \frac{R3}{R2} \sqrt{\frac{R2}{R4}}$$

$$H_{OHP} = \frac{-R2}{R1}$$

$$H_{OLP} = \frac{-R4}{R1}$$

$$H_{OBP} = \frac{-R3}{R1}$$

$$H_{ON1}(f \rightarrow 0Hz) = \frac{R_{G}}{R_{L}} \left(\frac{R4}{R1}\right)$$

$$H_{ON2}(at f = f_{CLK} / 2) = \frac{R_{G}}{R_{L}} \left(\frac{R2}{R1}\right)$$

Note: When the passband gain error exceeds 1dB, the use of capacitor C_C between the lowpass output and the inverting input will reduce the gain error. The value can best be determined experimentally. Typically, it should be about 5pF/dB (C_{C-MAX} = 15pF).

Offset Voltage

Switched-capacitor integrators generally exhibit higher input offsets than discrete RC integrators. The larger offset is mainly due to the charge injection of the CMOS switches into the integrating capacitors. The internal op amp offset also adds to the overall offset value. Figure 8 shows the input offsets from a single 2nd-order section. Table 4 lists the formula for the output offset voltage for various modes and output pins.

Power Supplies

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The MAX7490 operates from a single +5V supply, and the MAX7491 operates from a single +3V supply. Bypass V_{DD} to GND with at least a 0.1 μ F capacitor. V_{DD} should be isolated from other digital or high-voltage analog supplies. If dual supplies are required, connect the COM pin to the system ground and the GND pin to the negative supply. Figure 9 shows an example of dual-supply operation. Single-supply and dual-supply performances are equivalent. For dual-supply operation, drive CLK, SHDN, and EXTCLK from GND (which is now V-) to V_{DD}. If using the internal oscillator in dualsupply mode, C_{OSC} can be returned to either GND or the actual ground voltage. Use the MAX7490 for ±2.5V and use the MAX7491 for ±1.5V.

For most applications, a 0.1μ F bypass capacitor from COM to GND is sufficient. If the V_{DD} supply has significant 60Hz energy, increase this capacitor to 1μ F or greater to provide better power-supply rejection.

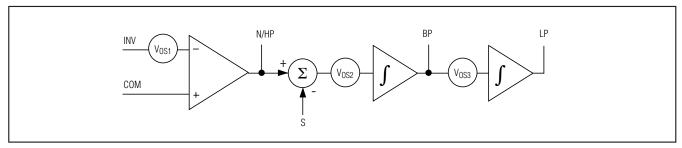


Figure 8. Block Diagram of a 2nd-Order Section Showing the Input Offsets

MODE	VOSN/HP	VOSBP	VOSLP
1	V _{OS1} [1 + (R2 / R3) + (R2 / R1)] - (V _{OS3}) (R2 / R3)	V _{OS3}	Vosn/HP - Vos2
1b	V _{OS1} [1 + (R2 / R3) + (R2 / R1)] - (V _{OS3}) (R2 / R3)	V _{OS3}	(V _{OSN/HP} - V _{OS2})[1 + R5 / R6)]
2	V _{OS1} [1 + (R2 / R3) + (R2 / R1) + (R2 / R4) - (V _{OS3})(R2 / R3)][R4 / R2 + R4] + (V _{OS2})[R2 / R2 + R4]	V _{OS3}	Vosn/HP - Vos2
3	V _{OS2}	V _{OS3}	V _{OS1} [1 + (R4 / R1) + (R4 / R2) + (R4 / R3)] - (V _{OS2}) (R4 / R2) - (V _{OS3})(R4 / R3)

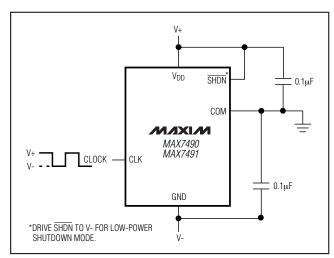


Figure 9. Dual-Supply Operation

Input Signal Amplitude Range

The optimal input signal range is determined by observing the voltage level at which the signal-to-noise plus distortion (SINAD) ratio is maximized for a given corner frequency. The *Typical Operating Characteristics* show the THD + Noise response as the input signal's peak-to-peak amplitude is varied. In most systems, the input signal should be kept as large as possible to maximize the signal-to-noise ratio (SNR). Allow sufficient headroom to ensure no signal clipping under expected operating conditions.

Anti-Aliasing and Post-DAC Filtering

When using the MAX7490/MAX7491 for anti-aliasing or post-DAC filtering, synchronize the DAC (or ADC) and the filter clocks. If the clocks are not synchronized, beat frequencies may alias into the desired passband.

Aliasing

MAX7490/MAX7491

Aliasing is an inherent phenomenon of most switchedcapacitor filters. As with all sampled systems, frequency components of the input signal above one half the sampling rate will be aliased. The MAX7490/MAX7491 sample at twice the clock frequency, yielding a 200:1 sampling to cutoff frequency ratio.

In particular, input signal components (f_{IN}) near the sampling rate generate a difference frequency (f_{SAMPLING} - f_{IN}) that often falls within the passband of the filter. Such aliased signals, when they appear at the output, are indistinguishable from real input information. For example, the aliased output signal generated when a 99kHz waveform is applied to a filter sampling at 100kHz, (f_{CLK} = 50kHz) is 1kHz. This waveform is an attenuated version of the output that would result from a true 1kHz input. Since sampling is done at twice the clock frequency, the Nyquist frequency is the same as the clock frequency.

A simple passive RC lowpass input filter is usually sufficient to remove input frequencies that can be aliased. In many cases, the input signal itself may be band limited and require no special anti-alias filtering. Selecting a passive filter cutoff frequency equal to fc/2 gives 12dB rejection at the Nyquist frequency.

Clock Feedthrough

Clock feedthrough is defined as the RMS value of the clock frequency and its harmonics that are present at the filter's output pins, even without input signal. The clock feedthrough can be greatly reduced by adding a simple RC lowpass network at the final filter output. Choose a cutoff frequency as low as possible to provide maximum noise attenuation. The attenuation and phase shift of the external filter will limit the actual frequency selected.



Table 5. Cascading Identical BandpassFilter Sections

TOTAL SECTIONS	TOTAL BW	TOTAL Q	
1	1.000 B	1.00 Q	
2	0.644 B	1.55 Q	
3	0.510 B	1.96 Q	
4	0.435 B	2.30 Q	
5	0.386 B	2.60 Q	

Multiple Filter Stages

In some designs, such as very narrow band filters, or in modes where fo cannot be tuned with resistors, several 2nd-order sections with identical fo may be cascaded without multiple feedback. The total Q of the resultant filter (Q_T) is:

Total Q_T = Q /
$$(2^{1/N} - 1)^{1/2}$$

Q is the Q of each individual filter section, and N is the number of 2nd-order sections. In Table 5, the total Q and total bandwidth (BW) are listed for up to five identical 2nd-order sections. B is the bandwidth of each section.

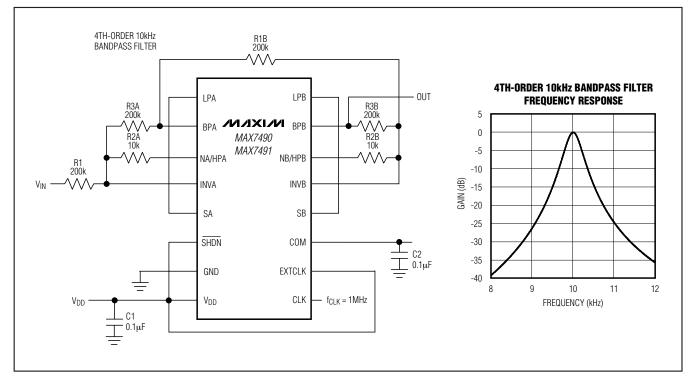
Chip Information

MXXIM

PROCESS: BICMOS

Wideband Noise

The wideband noise of the filter is the total RMS value of the device's noise spectral density and is used to determine the operating SNR. Most of its frequency contents lie within the filter's passband and cannot be reduced with postfiltering. The total noise depends mainly on the Q of each filter section and the cascade sequence. Therefore, in multistage filters, place the section with the highest Q first for lower output noise.



Typical Application Circuit

Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.	
16 QSOP	E16+4	<u>21-0055</u>	



MAX7490/MAX7491

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	7/00	Initial release	—
1	4/09	Changes to add lead-free packages, style edits	1–10, 16, 17, 18

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